

# 74LVC2G38GM,125 Datasheet



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DiGi Electronics Part Number 74LVC2G38GM,125-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number 74LVC2G38GM,125

Description IC GATE NAND 2CH 2-INP 8XQFN

Detailed Description NAND Gate IC 2 Channel Open Drain 8-XQFN (1.6x1

6)



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# **Purchase and inquiry**

| Manufacturer Product Number: | Manufacturer:                      |
|------------------------------|------------------------------------|
| 74LVC2G38GM,125              | Nexperia USA Inc.                  |
| Series:                      | Product Status:                    |
| 74LVC                        | Obsolete                           |
| Logic Type:                  | Number of Circuits:                |
| NAND Gate                    | 2                                  |
| Number of Inputs:            | Features:                          |
| 2                            | Open Drain                         |
| Voltage - Supply:            | Current - Quiescent (Max):         |
| 1.65V ~ 5.5V                 | 4 μΑ                               |
| Current - Output High, Low:  | Input Logic Level - Low:           |
| -, 32mA                      | 0.7V ~ 0.8V                        |
| Input Logic Level - High:    | Max Propagation Delay @ V, Max CL: |
| 1.7V ~ 2V                    | 3.3ns @ 5V, 50pF                   |
| Operating Temperature:       | Mounting Type:                     |
| -40°C ~ 125°C                | Surface Mount                      |
| Supplier Device Package:     | Package / Case:                    |
| 8-XQFN (1.6x1.6)             | 8-XFQFN Exposed Pad                |
| Base Product Number:         |                                    |
| 74LVC2G38                    |                                    |

# **Environmental & Export classification**

8542.39.0001

| RoHS Status:     | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant  | 1 (Unlimited)                     |
| REACH Status:    | ECCN:                             |
| REACH Unaffected | EAR99                             |
| HTSUS:           |                                   |

**Product data sheet** 

### 1. General description

The 74LVC2G38 is a dual 2-input NAND gate with open-drain outputs. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

#### 2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant outputs for interfacing with 5 V logic
- Overvoltage tolerant inputs to 5.5 V
- · High noise immunity
- CMOS low power dissipation
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- ±24 mA output drive (V<sub>CC</sub> = 3.0 V)
- · Open-drain outputs
- · Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



Dual 2-input NAND gate; open drain

# 3. Ordering information

**Table 1. Ordering information** 

| Type number | Package           |        |   |           |  |  |  |
|-------------|-------------------|--------|---|-----------|--|--|--|
|             | Temperature range | Name   | Description   | Version   |  |  |  |
| 74LVC2G38DP | -40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm                         | SOT505-2  |  |  |  |
| 74LVC2G38DC | -40 °C to +125 °C | VSSOP8 | plastic very thin shrink small outline package; 8 leads; body width 2.3 mm                                      | SOT765-1  |  |  |  |
| 74LVC2G38GT | -40 °C to +125 °C | XSON8  | plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm                     | SOT833-1  |  |  |  |
| 74LVC2G38GN | -40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads;<br>8 terminals; body 1.2 × 1.0 × 0.35 mm                        | SOT1116   |  |  |  |
| 74LVC2G38GS | -40 °C to +125 °C | XSON8  | extremely thin small outline package; no leads;<br>8 terminals; body 1.35 × 1.0 × 0.35 mm                       | SOT1203   |  |  |  |
| 74LVC2G38GX | -40 °C to +125 °C | X2SON8 | plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.32 mm | SOT1233-2 |  |  |  |

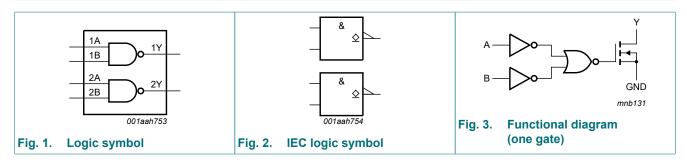
# 4. Marking

Table 2. Marking codes

| Type number | Marking code[1] |
|-------------|-----------------|
| 74LVC2G38DP | Y38             |
| 74LVC2G38DC | Y38             |
| 74LVC2G38GT | Y38             |
| 74LVC2G38GN | YB              |
| 74LVC2G38GS | YB              |
| 74LVC2G38GX | YB              |

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

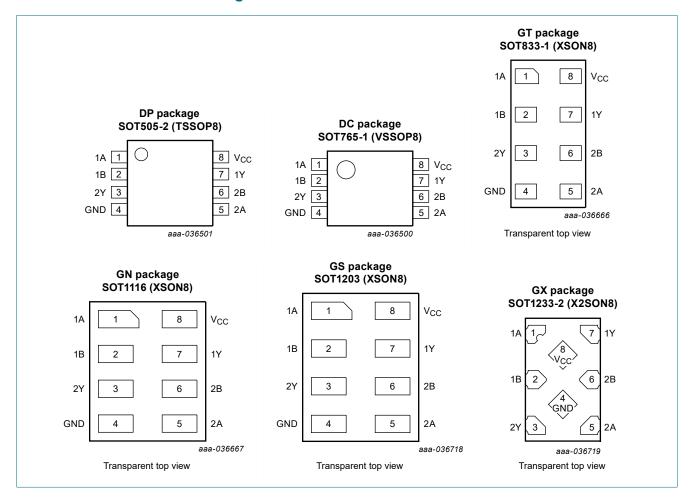
# 5. Functional diagram



Dual 2-input NAND gate; open drain

# 6. Pinning information

#### 6.1. Pinning



#### 6.2. Pin description

Table 3. Pin description

| Symbol          | Pin  | Description    |
|-----------------|------|----------------|
| 1A, 2A          | 1, 5 | data input     |
| 1B, 2B          | 2, 6 | data input     |
| GND             | 4    | ground (0 V)   |
| 1Y, 2Y          | 7, 3 | data output    |
| V <sub>CC</sub> | 8    | supply voltage |

Dual 2-input NAND gate; open drain

## 7. Functional description

#### **Table 4. Function table**

H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

| Input |    | Output |
|-------|----|--------|
| nA    | nB | nY     |
| L     | L  | Z      |
| L     | Н  | Z      |
| Н     | L  | Z      |
| Н     | Н  | L      |

### 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions   |     | Min  | Max                   | Unit |
|------------------|-------------------------|--|-----|------|-----------------------|------|
| V <sub>CC</sub>  | supply voltage          |  |     | -0.5 | +6.5                  | V    |
| VI               | input voltage           |  | [1] | -0.5 | +6.5                  | V    |
| Vo               | output voltage          | Active mode  | [1] | -0.5 | V <sub>CC</sub> + 0.5 | V    |
|                  |                         | Power-down mode; V <sub>CC</sub> = 0 V   | [1] | -0.5 | +6.5                  | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0 V   |     | -50  | -                     | mA   |
| I <sub>OK</sub>  | output clamping current | $V_O < 0 \text{ V or } V_O > V_{CC}$   |     | -    | ±50                   | mA   |
| Io               | output current          | $V_O = 0 V \text{ to } V_{CC}$   |     | -    | ±50                   | mA   |
| I <sub>CC</sub>  | supply current          |  |     | -    | 100                   | mA   |
| I <sub>GND</sub> | ground current          |  |     | -100 | -                     | mA   |
| T <sub>stg</sub> | storage temperature     |  |     | -65  | +150                  | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C   |     |      |                       |      |
|                  |                         | SOT505-2 (TSSOP8)<br>SOT765-1 (VSSOP8)<br>SOT833-1 (XSON8)<br>SOT1116 (XSON8)<br>SOT1203 (XSON8) | [2] | -    | 250                   | mW   |
|                  |                         | SOT1233-2 (X2SON8)   | [3] | -    | 300                   | mW   |

The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT833-1 (XSON8) package:  $P_{tot}$  derates linearly with 3.1 mW/K above 68  $^{\circ}\text{C}.$ 

For SOT1116 (XSON8) package:  $P_{tot}$  derates linearly with 4.2 mW/K above 90 °C. For SOT1203 (XSON8) package: Ptot derates linearly with 3.6 mW/K above 81 °C.

For SOT1233-2 (X2SON8) package:  $P_{tot}$  derates linearly with 7.7 mW/K above 118 °C.

For SOT505-2 (TSSOP8) package: P<sub>tot</sub> derates linearly with 4.6 mW/K above 96 °C. For SOT765-1 (VSSOP8) package:  $P_{tot}$  derates linearly with 4.9 mW/K above 99  $^{\circ}\text{C}.$ 

Dual 2-input NAND gate; open drain

# 9. Recommended operating conditions

#### **Table 6. Operating conditions**

| Symbol           | Parameter                           | Conditions                             | Min  | Max             | Unit |
|------------------|-------------------------------------|--|------|-----------------|------|
| $V_{CC}$         | supply voltage                      |  | 1.65 | 5.5             | V    |
| V <sub>I</sub>   | input voltage                       |  | 0    | 5.5             | V    |
| Vo               | output voltage                      | Active mode                            | 0    | V <sub>CC</sub> | V    |
|                  |                                     | disable mode                           | 0    | 5.5             | V    |
|                  |                                     | Power-down mode; V <sub>CC</sub> = 0 V | 0    | 5.5             | V    |
| T <sub>amb</sub> | ambient temperature                 |  | -40  | +125            | °C   |
| Δt/ΔV            | input transition rise and fall rate | V <sub>CC</sub> = 1.65 V to 2.7 V      | -    | 20              | ns/V |
| l                |                                     | V <sub>CC</sub> = 2.7 V to 5.5 V       | -    | 10              | ns/V |

### 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                | Parameter                 | Conditions   | Min                 | Typ[1] | Max                 | Unit |
|-----------------------|---------------------------|--|---------------------|--------|---------------------|------|
| T <sub>amb</sub> = -4 | 0 °C to +85 °C            |  |                     |        |                     |      |
| V <sub>IH</sub>       | HIGH-level input voltage  | V <sub>CC</sub> = 1.65 V to 1.95 V   | 0.65V <sub>CC</sub> | -      | -                   | V    |
|                       |                           | V <sub>CC</sub> = 2.3 V to 2.7 V   | 1.7                 | -      | -                   | V    |
|                       |                           | V <sub>CC</sub> = 2.7 V to 3.6 V   | 2.0                 | -      | -                   | V    |
|                       |                           | V <sub>CC</sub> = 4.5 V to 5.5 V   | 0.7V <sub>CC</sub>  | -      | -                   | V    |
| V <sub>IL</sub>       | LOW-level input voltage   | V <sub>CC</sub> = 1.65 V to 1.95 V   | -                   | -      | 0.35V <sub>CC</sub> | V    |
|                       |                           | V <sub>CC</sub> = 2.3 V to 2.7 V   | -                   | -      | 0.7                 | V    |
|                       |                           | V <sub>CC</sub> = 2.7 V to 3.6 V   | -                   | -      | 0.8                 | V    |
|                       |                           | V <sub>CC</sub> = 4.5 V to 5.5 V   | -                   | -      | 0.3V <sub>CC</sub>  | V    |
| V <sub>OL</sub>       | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |                     |        |                     |      |
|                       |                           | $I_{O}$ = 100 $\mu$ A; $V_{CC}$ = 1.65 V to 5.5 V  | -                   | -      | 0.1                 | V    |
|                       |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V  | -                   | 0.08   | 0.45                | V    |
|                       |                           | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V   | -                   | 0.14   | 0.3                 | V    |
|                       |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V  | -                   | 0.19   | 0.4                 | V    |
|                       |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V  | -                   | 0.37   | 0.55                | V    |
|                       |                           | I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V  | -                   | 0.43   | 0.55                | V    |
| I <sub>I</sub>        | input leakage current     | $V_{I} = 5.5 \text{ V or GND}; V_{CC} = 0 \text{ V to } 5.5 \text{ V}$                                       | -                   | ±0.1   | ±1                  | μA   |
| l <sub>OZ</sub>       | OFF-state output current  | $V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$                                 | -                   | ±0.1   | ±2                  | μΑ   |
| I <sub>OFF</sub>      | power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 0 V  | -                   | ±0.1   | ±2                  | μA   |
| I <sub>CC</sub>       | supply current            | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 1.65 V to 5.5 V; I <sub>O</sub> = 0 A                    | -                   | 0.1    | 4                   | μΑ   |
| ΔI <sub>CC</sub>      | additional supply current | per pin; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V;<br>V <sub>CC</sub> = 2.3 V to 5.5 V; I <sub>O</sub> = 0 A | -                   | 5      | 500                 | μA   |
| Cı                    | input capacitance         |  | -                   | 2.5    | -                   | pF   |

| Symbol                | Parameter                 | Conditions   | Min                 | Typ[1] | Max                 | Unit |
|-----------------------|---------------------------|--|---------------------|--------|---------------------|------|
| T <sub>amb</sub> = -4 | 10 °C to +125 °C          |  |                     |        |                     |      |
| V <sub>IH</sub>       | HIGH-level input voltage  | V <sub>CC</sub> = 1.65 V to 1.95 V   | 0.65V <sub>CC</sub> | -      | -                   | V    |
|                       |                           | V <sub>CC</sub> = 2.3 V to 2.7 V   | 1.7                 | -      | -                   | V    |
|                       |                           | V <sub>CC</sub> = 2.7 V to 3.6 V   | 2.0                 | -      | -                   | V    |
|                       |                           | V <sub>CC</sub> = 4.5 V to 5.5 V   | 0.7V <sub>CC</sub>  | -      | -                   | V    |
| V <sub>IL</sub>       | LOW-level input voltage   | V <sub>CC</sub> = 1.65 V to 1.95 V   | -                   | -      | 0.35V <sub>CC</sub> | V    |
|                       |                           | V <sub>CC</sub> = 2.3 V to 2.7 V   | -                   | -      | 0.7                 | V    |
|                       |                           | V <sub>CC</sub> = 2.7 V to 3.6 V   | -                   | -      | 8.0                 | V    |
|                       |                           | V <sub>CC</sub> = 4.5 V to 5.5 V   | -                   | -      | 0.3V <sub>CC</sub>  | V    |
| V <sub>OL</sub>       | LOW-level output voltage  | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |                     |        |                     |      |
|                       |                           | I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 1.65 V to 5.5 V   | -                   | -      | 0.1                 | V    |
|                       |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V  | -                   | -      | 0.70                | V    |
|                       |                           | I <sub>O</sub> = 8 mA; V <sub>CC</sub> = 2.3 V   | -                   | -      | 0.45                | V    |
|                       |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V  | -                   | -      | 0.60                | V    |
|                       |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V  | -                   | -      | 0.80                | V    |
|                       |                           | I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V  | -                   | -      | 0.80                | V    |
| l <sub>l</sub>        | input leakage current     | $V_{I} = 5.5 \text{ V or GND}; V_{CC} = 0 \text{ V to } 5.5 \text{ V}$                                       | -                   | -      | ±1                  | μΑ   |
| l <sub>OZ</sub>       | OFF-state output current  | $V_I = V_{IH}$ or $V_{IL}$ ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$                                 | -                   | ±0.1   | ±2                  | μA   |
| I <sub>OFF</sub>      | power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 5.5 V; V <sub>CC</sub> = 0 V  | -                   | -      | ±2                  | μΑ   |
| I <sub>CC</sub>       | supply current            | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 1.65 V to 5.5 V; I <sub>O</sub> = 0 A                    | -                   | -      | 4                   | μA   |
| ΔI <sub>CC</sub>      | additional supply current | per pin; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V;<br>V <sub>CC</sub> = 2.3 V to 5.5 V; I <sub>O</sub> = 0 A | -                   | -      | 500                 | μA   |

<sup>[1]</sup> All typical values are measured at  $T_{amb}$  = 25 °C.

Dual 2-input NAND gate; open drain

# 11. Dynamic characteristics

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground 0 V); for test circuit see Fig. 5.

| Symbol           | Parameter                     | Conditions                            | -40 | °C to +85 ° | ,C  | -40 °C to | +125 °C | Unit |
|------------------|-------------------------------|---------------------------------------|-----|-------------|-----|-----------|---------|------|
|                  |                               |                                       | Min | Typ [1]     | Max | Min       | Max     |      |
| t <sub>PZL</sub> | OFF-state to LOW              | nA, nB to nY; see Fig. 4              |     |             |     |           |         |      |
|                  | propagation delay             | V <sub>CC</sub> = 1.65 V to 1.95 V    | 1.2 | 3.0         | 8.6 | 1.2       | 10.8    | ns   |
|                  |                               | V <sub>CC</sub> = 2.3 V to 2.7 V      | 0.7 | 1.8         | 4.8 | 0.7       | 6.0     | ns   |
|                  |                               | V <sub>CC</sub> = 2.7 V               | 0.7 | 2.5         | 4.4 | 0.7       | 5.5     | ns   |
|                  |                               | V <sub>CC</sub> = 3.0 V to 3.6 V      | 0.7 | 2.1         | 4.1 | 0.7       | 5.2     | ns   |
|                  |                               | V <sub>CC</sub> = 4.5 V to 5.5 V      | 0.5 | 1.5         | 3.3 | 0.5       | 4.2     | ns   |
| t <sub>PLZ</sub> | LOW to OFF-state              | nA, nB to nY; see Fig. 4              |     |             |     |           |         |      |
|                  | propagation delay             | V <sub>CC</sub> = 1.65 V to 1.95 V    | 1.2 | 3.0         | 8.6 | 1.2       | 10.8    | ns   |
|                  |                               | V <sub>CC</sub> = 2.3 V to 2.7 V      | 0.7 | 1.8         | 4.8 | 0.7       | 6.0     | ns   |
|                  |                               | V <sub>CC</sub> = 2.7 V               | 0.7 | 2.5         | 4.4 | 0.7       | 5.5     | ns   |
|                  |                               | V <sub>CC</sub> = 3.0 V to 3.6 V      | 0.7 | 2.1         | 4.1 | 0.7       | 5.2     | ns   |
|                  |                               | V <sub>CC</sub> = 4.5 V to 5.5 V      | 0.5 | 1.5         | 3.3 | 0.5       | 4.2     | ns   |
| C <sub>PD</sub>  | power dissipation capacitance | per gate; $V_I = GND$ to $V_{CC}$ [2] | -   | 5           | -   | -         | -       | pF   |

- [1] Typical values are measured at nominal  $V_{CC}$  and at  $T_{amb}$  = 25 °C.
- [2]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

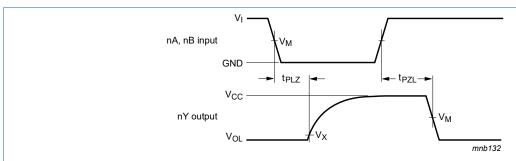
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

#### 11.1. Waveforms and test circuit



Measurement points are given in Table 9

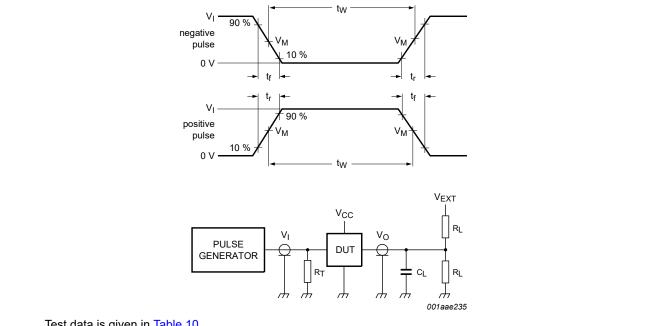
V<sub>OL</sub> is a typical output voltage level that occurs with the output load.

Fig. 4. Inputs nA and nB to output nY propagation delay times

#### Dual 2-input NAND gate; open drain

**Table 9. Measurement points** 

| Supply voltage   | Input              | Output                   | Output             |  |  |
|------------------|--------------------|--------------------------|--------------------|--|--|
| V <sub>CC</sub>  | V <sub>M</sub>     | V <sub>X</sub>           | V <sub>M</sub>     |  |  |
| 1.65 V to 1.95 V | 0.5V <sub>CC</sub> | V <sub>OL</sub> + 0.15 V | 0.5V <sub>CC</sub> |  |  |
| 2.3 V to 2.7 V   | 0.5V <sub>CC</sub> | V <sub>OL</sub> + 0.15 V | 0.5V <sub>CC</sub> |  |  |
| 2.7 V            | 1.5 V              | V <sub>OL</sub> + 0.3 V  | 1.5 V              |  |  |
| 3.0 V to 3.6 V   | 1.5 V              | V <sub>OL</sub> + 0.3 V  | 1.5 V              |  |  |
| 4.5 V to 5.5 V   | 0.5V <sub>CC</sub> | V <sub>OL</sub> + 0.3 V  | 0.5V <sub>CC</sub> |  |  |



Test data is given in Table 10

Definitions for test circuit:

R<sub>L</sub> = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator;

 $V_{EXT}$  = External voltage for measuring switching times;

Test circuit for measuring switching times Fig. 5.

Table 10. Test data

| Supply voltage   | Input           |                                 | Load  |       | V <sub>EXT</sub>      |
|------------------|-----------------|---------------------------------|-------|-------|-----------------------|
| V <sub>CC</sub>  | V <sub>I</sub>  | t <sub>r</sub> , t <sub>f</sub> | CL    | $R_L$ | $t_{PLZ}$ , $t_{PZL}$ |
| 1.65 V to 1.95 V | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF | 1 kΩ  | 2V <sub>CC</sub>      |
| 2.3 V to 2.7 V   | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF | 500 Ω | 2V <sub>CC</sub>      |
| 2.7 V            | 2.7 V           | ≤ 2.5 ns                        | 50 pF | 500 Ω | 6 V                   |
| 3.0 V to 3.6 V   | 2.7 V           | ≤ 2.5 ns                        | 50 pF | 500 Ω | 6 V                   |
| 4.5 V to 5.5 V   | V <sub>CC</sub> | ≤ 2.5 ns                        | 50 pF | 500 Ω | 2V <sub>CC</sub>      |

Dual 2-input NAND gate; open drain

# 12. Package outline

#### TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

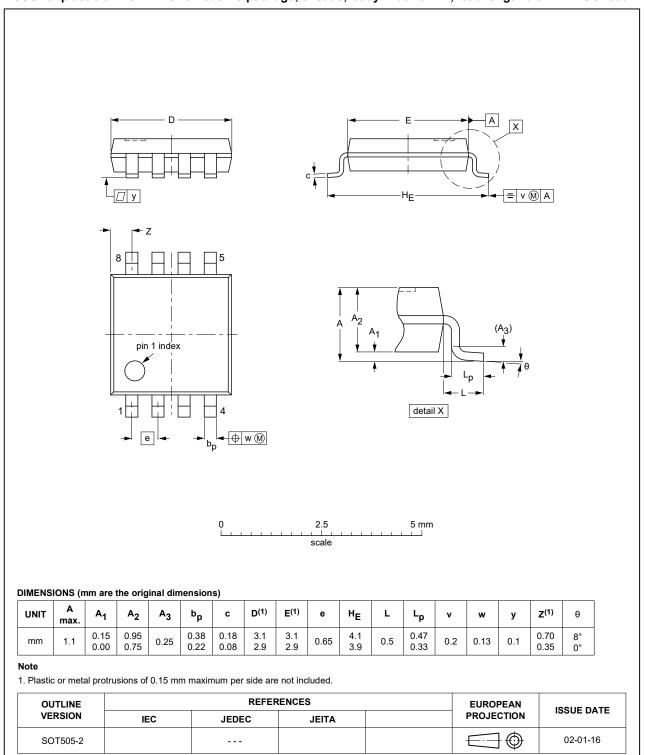


Fig. 6. Package outline SOT505-2 (TSSOP8)

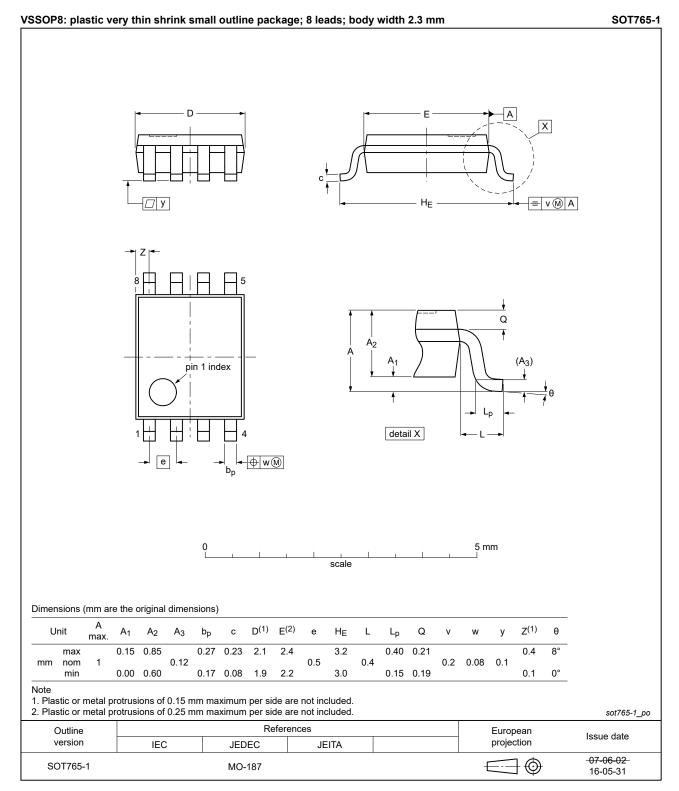


Fig. 7. Package outline SOT765-1 (VSSOP8)

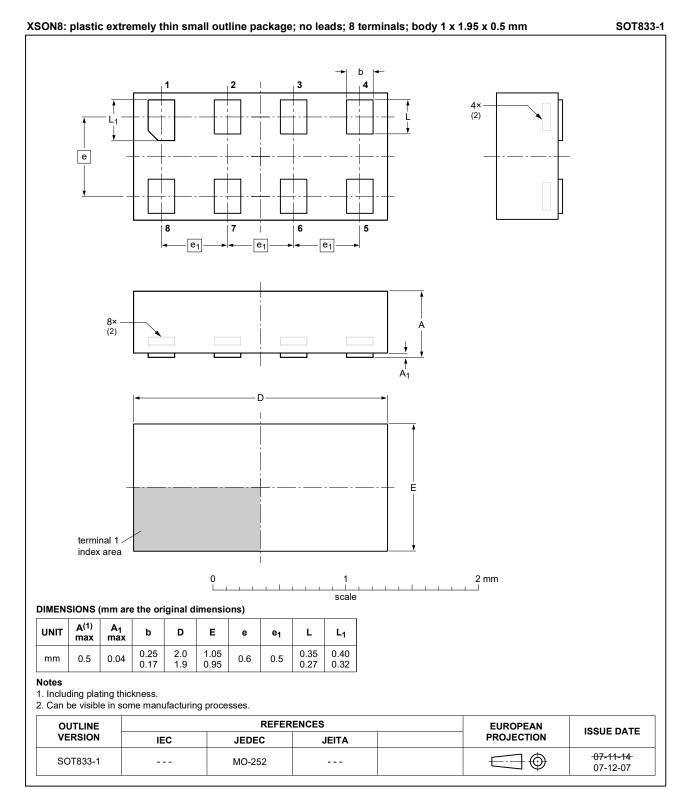


Fig. 8. Package outline SOT833-1 (XSON8)

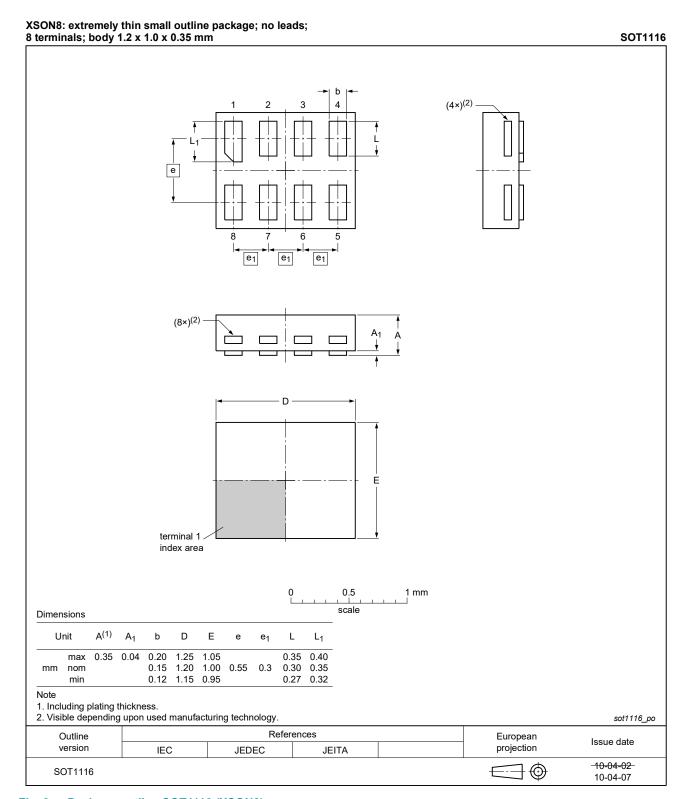


Fig. 9. Package outline SOT1116 (XSON8)

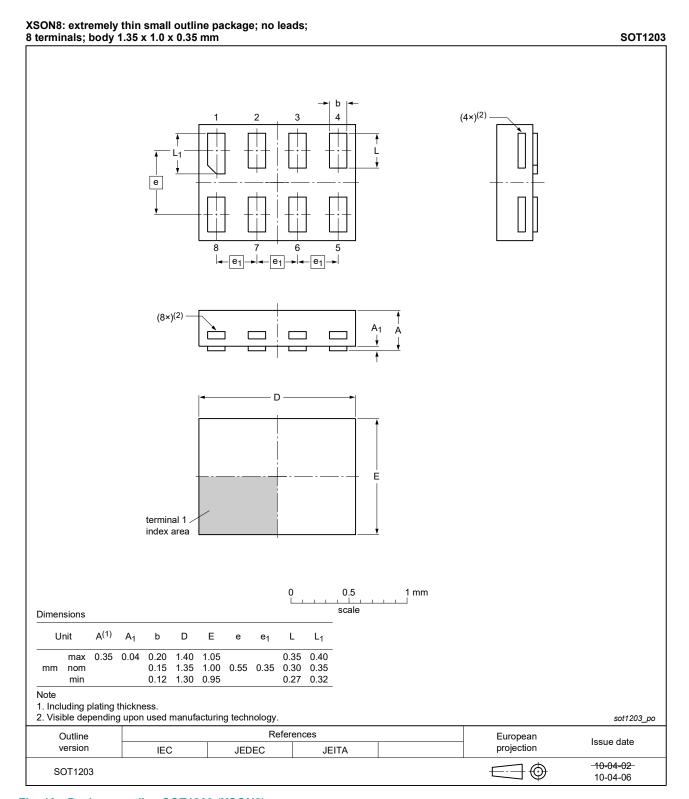


Fig. 10. Package outline SOT1203 (XSON8)

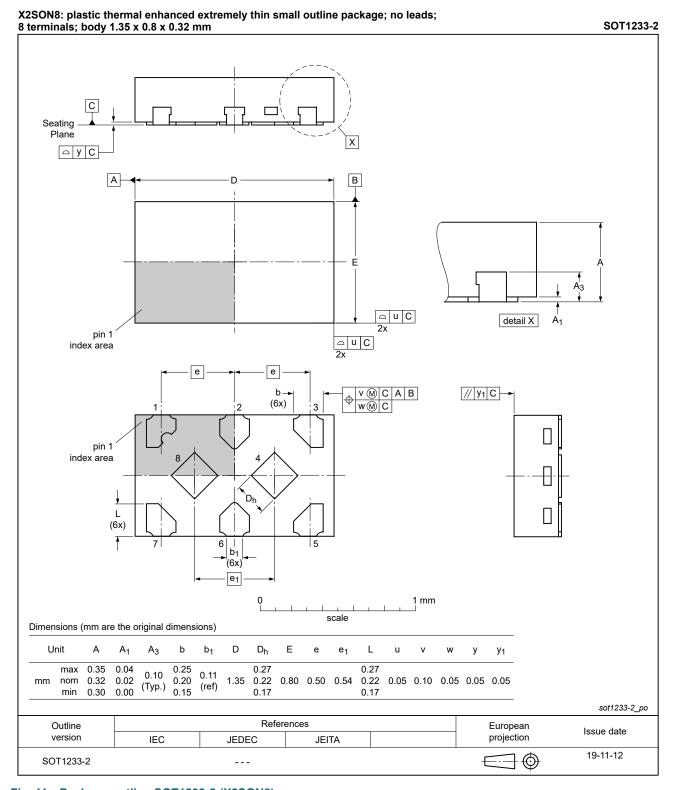


Fig. 11. Package outline SOT1233-2 (X2SON8)

Dual 2-input NAND gate; open drain

### 13. Abbreviations

#### **Table 11. Abbreviations**

| Acronym | Description                             |
|---------|---|
| CDM     | Charged Device Model                    |
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| НВМ     | Human Body Model                        |
| TTL     | Transistor-Transistor Logic             |

# 14. Revision history

#### Table 12. Revision history

| Document ID    | Release date                          | Data sheet status  | Change notice | Supersedes     |  |  |
|----------------|---------------------------------------|--|---------------|----------------|--|--|
| 74LVC2G38 v.16 | 20240430                              | Product data sheet   | -             | 74LVC2G38 v.15 |  |  |
| Modifications: | Type number                           | Type number 74LVC2G38GF (SOT1089/XSON8) removed.   |               |                |  |  |
| 74LVC2G38 v.15 | 20230828                              | Product data sheet   | -             | 74LVC2G38 v.14 |  |  |
| Modifications: |                                       | GOOTH TO THE PROPERTY OF THE P |               |                |  |  |
| 74LVC2G38 v.14 | 20220621                              | Product data sheet   | -             | 74LVC2G38 v.13 |  |  |
| Modifications: | • SOT1233 (X                          | <ul> <li><u>Section 1</u> and <u>Section 2</u> updated.</li> <li>SOT1233 (X2SON8) package changed to SOT1233-2 (X2SON8) package.</li> <li><u>Table 5</u>: P<sub>tot</sub> total power dissipation and derating values have been updated.</li> </ul>  |               |                |  |  |
| 74LVC2G38 v.13 | 20170703                              | Product data sheet   | -             | 74LVC2G38 v.12 |  |  |
| Modifications: | guidelines of Legal texts  Added type | <ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Added type number 74LVC2G38GX (SOT1233 / X2SON8).</li> <li>Type number 74LVC2G38GD removed.</li> </ul>   |               |                |  |  |
| 74LVC2G38 v.12 | 20161215                              | Product data sheet   | -             | 74LVC2G38 v.11 |  |  |
| Modifications: | • <u>Table 7</u> : The                | <u>Table 7</u> : The maximum limits for leakage current and supply current have changed.   |               |                |  |  |
| 74LVC2G38 v.11 | 20130408                              | Product data sheet   | -             | 74LVC2G38 v.10 |  |  |
| Modifications: | For type nu                           | For type number 74LVC2G38GD XSON8U has changed to XSON8.   |               |                |  |  |
| 74LVC2G38 v.10 | 20120628                              | Product data sheet   | -             | 74LVC2G38 v.9  |  |  |
| Modifications: | For type nu                           | For type number 74LVC2G38GM the SOT code has changed to SOT902-2.  |               |                |  |  |
| 74LVC2G38 v.9  | 20111128                              | Product data sheet   | -             | 74LVC2G38 v.8  |  |  |
| Modifications: | Legal pages                           | Legal pages updated.   |               |                |  |  |
| 74LVC2G38 v.8  | 20101104                              | Product data sheet   | -             | 74LVC2G38 v.7  |  |  |
| 74LVC2G38 v.7  | 20090320                              | Product data sheet   | -             | 74LVC2G38 v.6  |  |  |
| 74LVC2G38 v.6  | 20080219                              | Product data sheet   | -             | 74LVC2G38 v.5  |  |  |
| 74LVC2G38 v.5  | 20070904                              | Product data sheet   | -             | 74LVC2G38 v.4  |  |  |
| 74LVC2G38 v.4  | 20060516                              | Product data sheet   | -             | 74LVC2G38 v.3  |  |  |
| 74LVC2G38 v.3  | 20050201                              | Product specification  | -             | 74LVC2G38 v.2  |  |  |
| 74LVC2G38 v.2  | 20041018                              | Product specification  | -             | 74LVC2G38 v.1  |  |  |

#### Dual 2-input NAND gate; open drain

### 15. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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74LVC2G38

#### Dual 2-input NAND gate; open drain

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